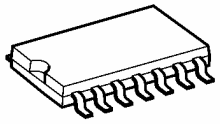
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC74F,TC74VHC74FN,TC74VHC74FT,TC74VHC74FK

Dual D-Type Flip-Flop with Preset and Clear

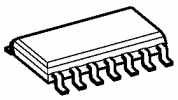
Note: The JEDEC SOP (FN) is not available in Japan.

TC74VHC74F



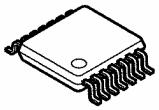
SOP14-P-300-1.27A

TC74VHC74FN



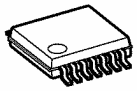
SOL14-P-150-1.27

TC74VHC74FT



TSSOP14-P-0044-0.65A

TC74VHC74FK



VSSOP14-P-0030-0.50

The TC74VHC74 is an advanced high speed CMOS D-FLIP FLOP fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The signal level applied to the D INPUT is transferred to Q OUTPUT during the positive going transition of the CK pulse.

$\overline{CLR}$ and $\overline{PR}$ are independent of the CK and are accomplished by setting the appropriate input low.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

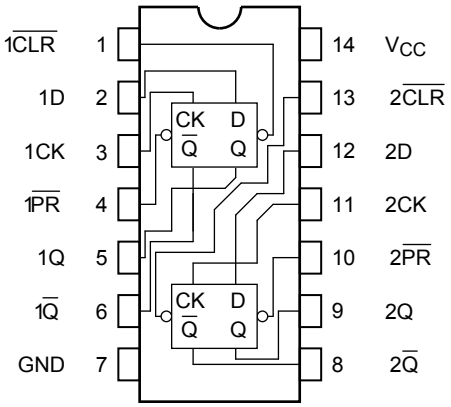
Features

- High speed: f_{max} = 170 MHz (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 2 μA (max) at Ta = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC\ (opr)}$ = 2 V to 5.5 V
- Pin and function compatible with 74ALS74

Weight

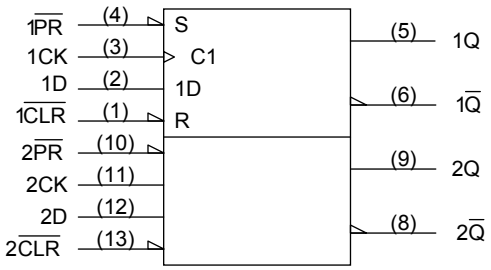
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)
VSSOP14-P-0030-0.50	: 0.02 g (typ.)

Pin Assignment



(top view)

IEC Logic Symbol



Truth Table

Inputs				Outputs		Function
$\overline{CLR}$	$\overline{PR}$	D	CK	Q	$\overline{Q}$	
L	H	X	X	L	H	Clear
H	L	X	X	H	L	Preset
L	L	X	X	H	H	—
H	H	L	↑	L	H	—
H	H	H	↑	H	L	—
H	H	X	↓	Q_n	$\overline{Q}_n$	No Change

X: Don't care

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to 7.0	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V_{CC} = 3.3 ± 0.3 V) 0 to 20 (V_{CC} = 5 ± 0.5 V)	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C				Ta = −40 to 85°C		Unit
				V_{CC} (V)	Min	Typ.	Max	Min	Max	
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
				3.0 to 5.5	V_{CC} × 0.7	—	—	V_{CC} × 0.7	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	—	0.50	V
				3.0 to 5.5	—	—	V_{CC} × 0.3	—	V_{CC} × 0.3	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
			I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
			I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	2.0	—	20.0	μA

Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = −40 to 85°C	Unit
			V_{CC} (V)	Limit	Limit	
Minimum pulse width (CK)	$t_{w\,(L)}$ $t_{w\,(H)}$	—	3.3 ± 0.3 5.0 ± 0.5	6.0 5.0	7.0 5.0	ns
Minimum pulse width ($\overline{CLR}$, $\overline{PR}$)	$t_{w\,(L)}$	—	3.3 ± 0.3 5.0 ± 0.5	6.0 5.0	7.0 5.0	ns
Minimum set-up time	t_s	—	3.3 ± 0.3 5.0 ± 0.5	6.0 5.0	7.0 5.0	ns
Minimum hold time	t_h	—	3.3 ± 0.3 5.0 ± 0.5	0.5 0.5	0.5 0.5	ns
Minimum removal time ($\overline{CLR}$, $\overline{PR}$)	t_{rem}	—	3.3 ± 0.3 5.0 ± 0.5	5.0 3.0	5.0 3.0	ns

AC Characteristics (input: $t_r = t_f = 3$ ns)

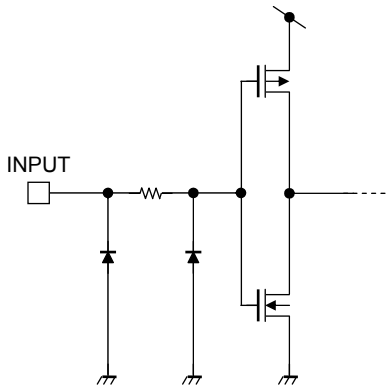
Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (CK-Q, $\overline{Q}$)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	6.7	11.9	1.0	14.0	ns
				50	—	9.2	15.4	1.0	17.5	
			5.0 ± 0.5	15	—	4.6	7.3	1.0	8.5	
				50	—	6.1	9.3	1.0	10.5	
Propagation delay time ($\overline{CLR}$, $\overline{PR}$-Q, $\overline{Q}$)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	7.6	12.3	1.0	14.5	ns
				50	—	10.1	15.8	1.0	18.0	
			5.0 ± 0.5	15	—	4.8	7.7	1.0	9.0	
				50	—	6.3	9.7	1.0	11.0	
Maximum clock frequency	f_{max}	—	3.3 ± 0.3	15	80	125	—	70	—	MHz
				50	50	75	—	45	—	
			5.0 ± 0.5	15	130	170	—	110	—	
				50	90	115	—	75	—	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note)			—	25	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

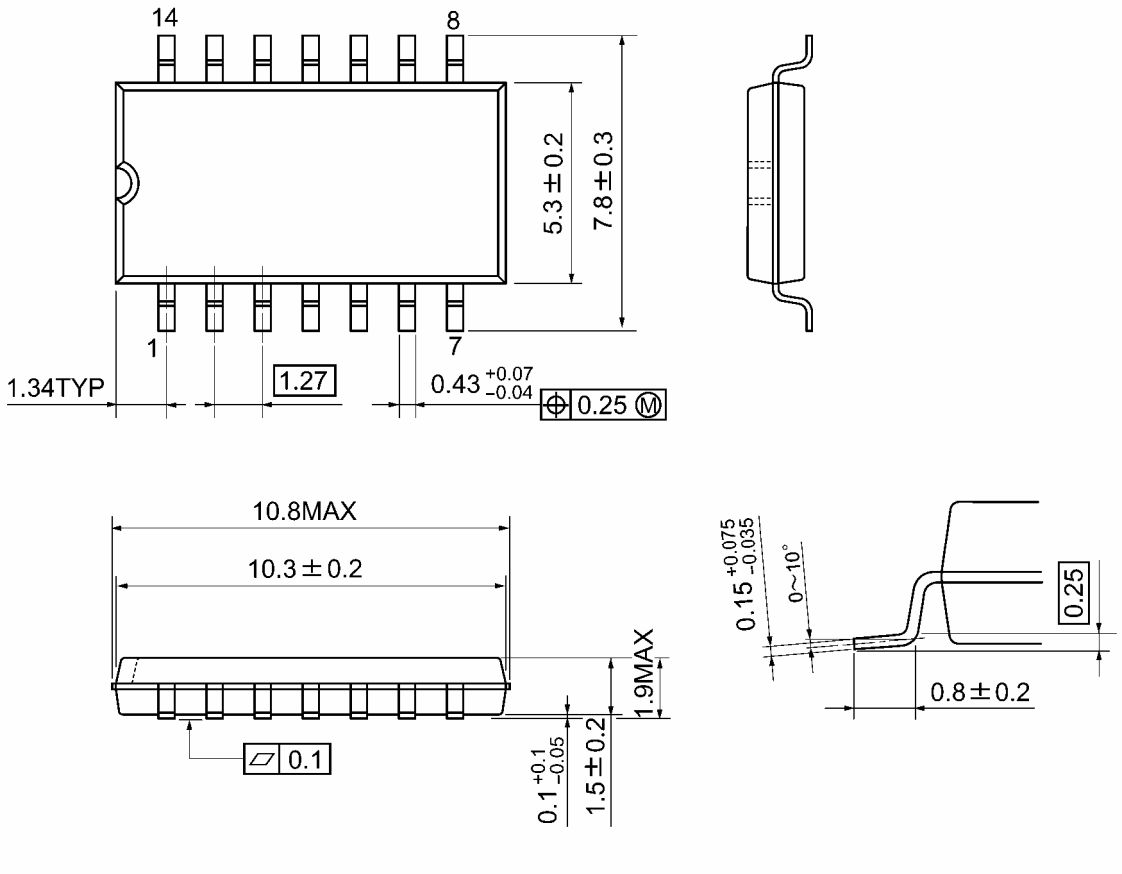
$$I_{CC\,(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per F/F)}$$

Input Equivalent Circuit



Package Dimensions

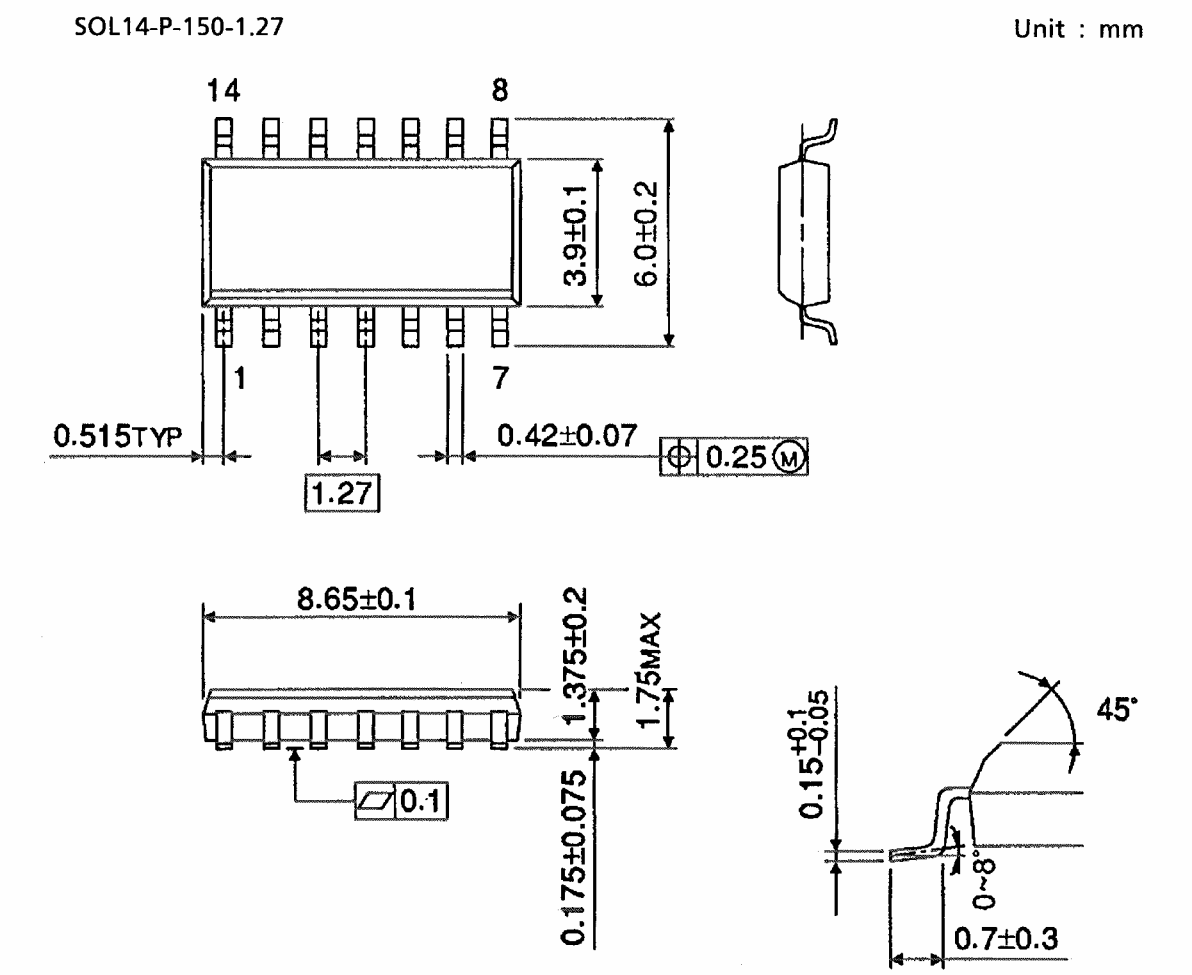
SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27 Unit : mm

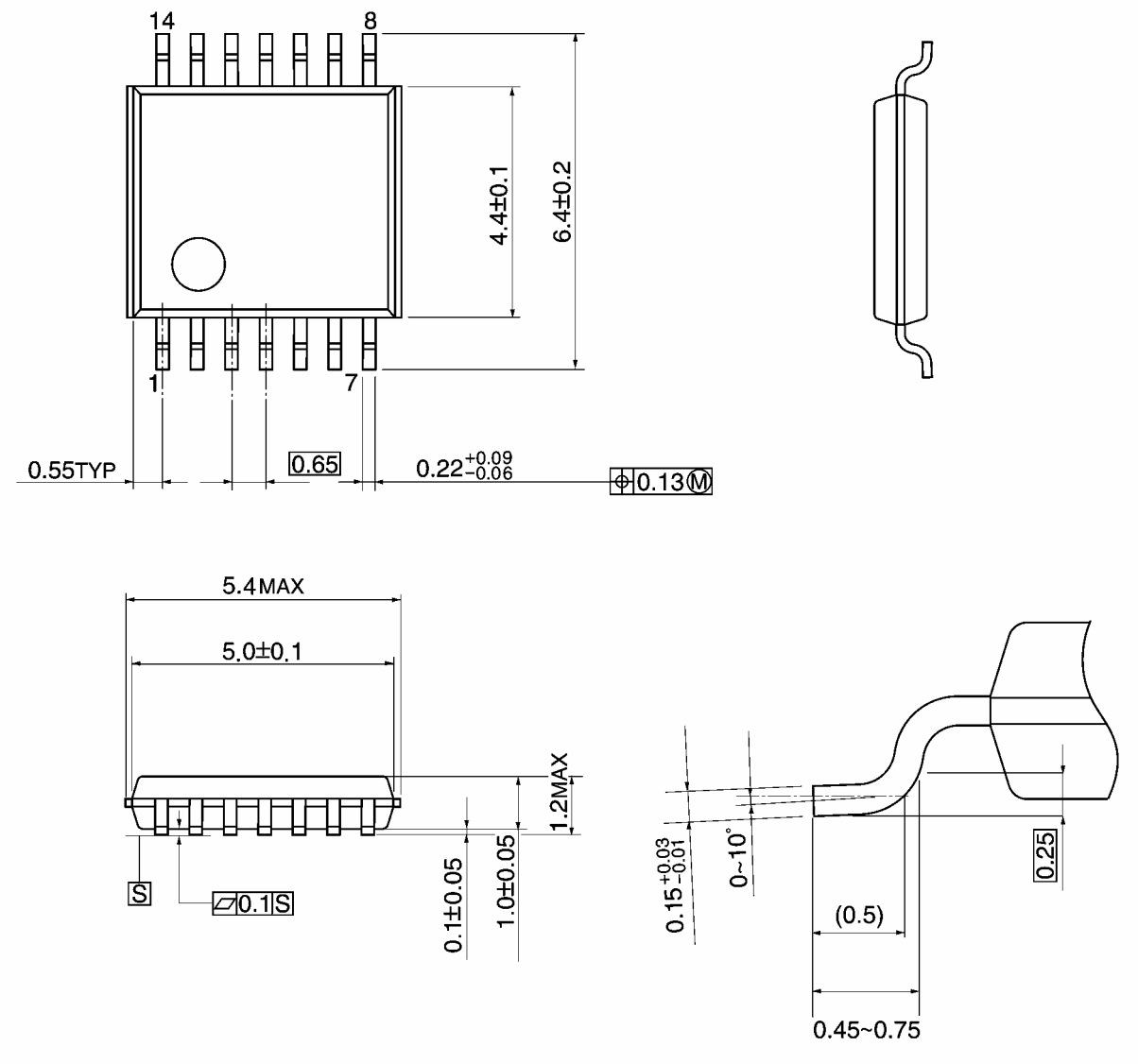


Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

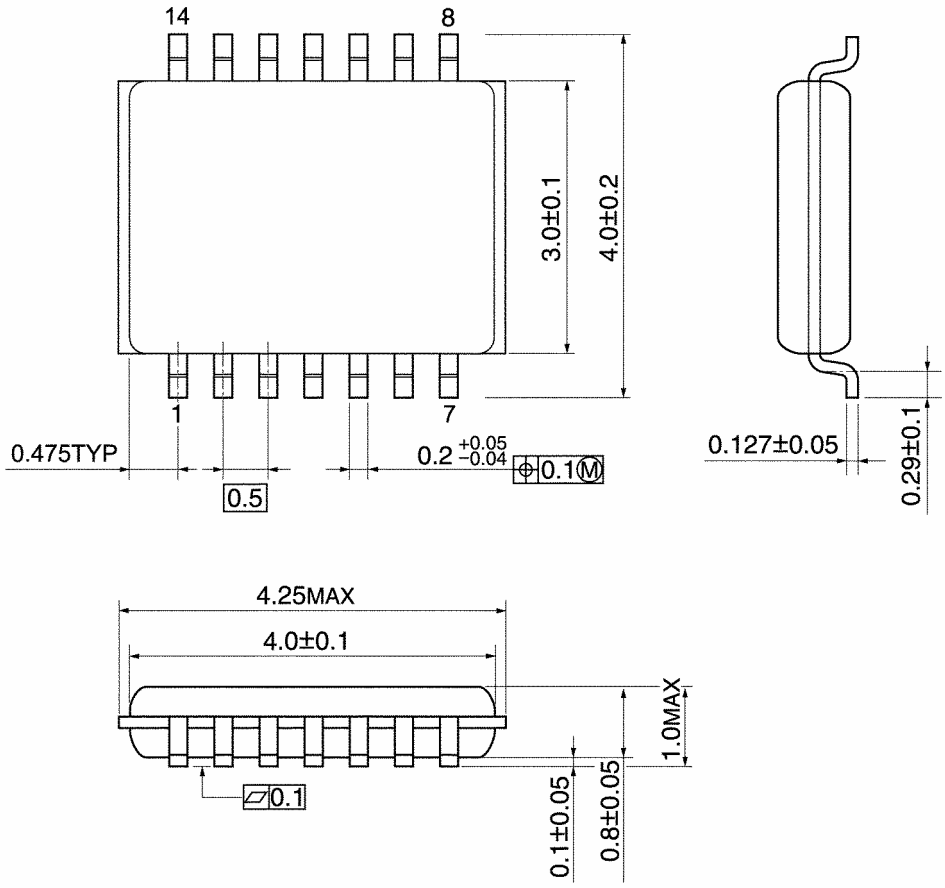
TSSOP14-P-0044-0.65A Unit: mm



Weight: 0.06 g (typ.)

Package Dimensions

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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